This is intended as a review paper only and it summarizes work which has been submitted for publication in the *IEEE Transactions on MTT*.

PROGRESS IN INTEGRATED-CIRCUIT HORN ANTENNAS FOR RECEIVER APPLICATIONS

PART 1: Antenna Design

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ABSTRACT

The purpose of this work is to present a systematic method for the design of multimode quasintegrated horn antennas. The design methodology is based on the Gaussian beam approach and the structures are optimized for achieving maximum fundamental Gaussian coupling efficiences. For this purpose, a hybrid technique is employed in which the integrated part of the antennasis treated using full-wave analysis, whereas the machined part is treated using an approximate method. This results in a simple and efficient design process. The developed design procedure has been applied for the design of a 20dB, a 23dB and a 25dB quasi-integrated horn antennasiall with a Gaussian coupling efficient exceeding 97%. The designed antennas have been tested and characterized using both full-wave analysis and 90GHz/370GHz measurements.

I. QUASI-INTEGRATED HORN ANTENNA DESIGN: INTRODUCTION

The integrated-circuit horn antenna was introduced in [1] and analyzed using a full-wave analysis technique in [2]. It consists of a dipole (or monopole) feed evaporated on a thin dielectric membrane which is suspended in a pyramidal cavity etched in silicon or GaAs. Recently, this antenna has been used in several millimeter and submillimeter-wave applications including a double-polarized antenna design at 93GHz [4], a 256 element imaging array at 802GHz [5], and a monopulse tracking system at 94GHz [6]. However, the wide flare-angle of the integratedcircuit horn antenna, which is dictated by the anisotropic etching involved in its fabrication (70° in silicon), limits its useful aperture size to 1.6λ and its gain to 13dB. To this end the quasi-integrated horn antenna was introduced [3], which consists of a machined small flareangle pyramidal section attached to the integrated portion (fig.1). The resulting structure is a simple multimode pyramidal horn with circularly symmetric patterns, high gain, and low crosspolarization, which is particularly attractive for submillimeter quasi-optical receiver applications. The minimum machined dimension involved in its fabrication is around 1.5λ which enables its fabrication to frequencies up to 2THz. The purpose of this paper is to describe a systematic approach towards the design of these horn antennas, and to provide a full range of practical quasi-integrated horn antenna designs along with their detailed radiation characteristics. Since a very desirable property of antennas intended for use in quasi-optical systems is the high Gaussian content of their radiated fields [7], the developed design methodology is based on the optimization of the quasi-integrated horns for achieving maximum fundamental Gaussian coupling efficiency. The Gaussian coupling efficiency is particularly important in quasi-optical receiver applications because it directly influences the total system performance with a pronounced effect on the receiver noise temperature [8].

II. MULTIMODE APERTURE ANALYSIS FOR MAXIMUM FUNDAMENTAL COUPLING EFFICIENCY

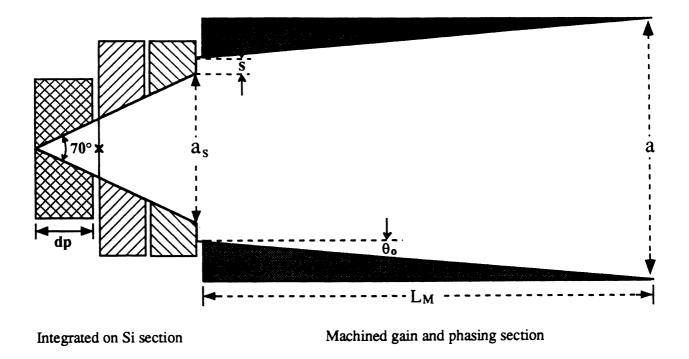


Fig.1 The general configuration of the quasi-integrated multimode horn antenna.

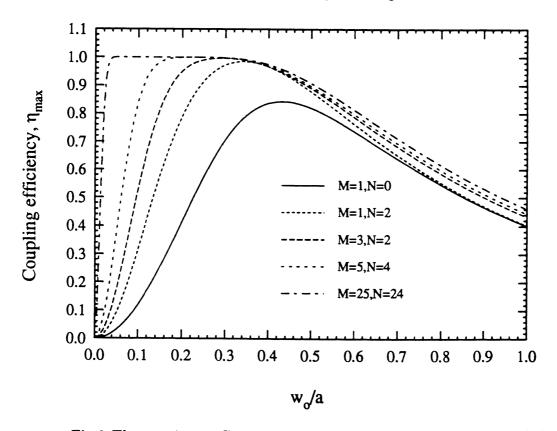


Fig.2 The maximum Gaussian coupling efficiency as a function of the w_o/a ratio for various aperture modes available for beamshaping (up to $\mathrm{TE}_{\mathrm{M,N}}/\mathrm{TM}_{\mathrm{M,N}}$, $\mathrm{m}=1,3\ldots\mathrm{M},\ \mathrm{n}=0,2\ldots\mathrm{N}$).

Consider a square aperture of side a in a ground-plane which is radiating in the half-space z > 0. The transverse electric field of the aperture at z = 0 can be expanded in terms of the eigenfunctions of a square waveguide of the same side a:

$$\bar{E}_{t,ap}(x,y) = \sum_{m,n}^{M,N} \{ A_{mn} \bar{e}_{mn}^{TE}(x,y) + C_{mn} \bar{e}_{mn}^{TM}(x,y) \} . \tag{1}$$

In (1) it is assumed that only modes with indices (m = 1, 3, 5...M) and n = 0, 2, 4, 6...N) are present as is the case of a pyramidal horn which is either fed by a centered Hertzian dipole or by a waveguide which supports only the dominant TE_{10} mode [2]. We now proceed to determine the modal coefficients A_{mn} , B_{mn} so that the coupling between the aperture field and a fundamental beam is maximized. If the copolarized and cross-polarized components of the aperture field are defined to be the $\bar{E}_{x,ap}$ and the $\bar{E}_{y,ap}$ components respectively, then the transverse electric field can be rewritten in the form:

$$E_{y,ap}(x,y) = \sum_{m,n}^{M,N} d_{mn}^{co} \Psi_{mn}^{co}(x,y) \quad , E_{x,ap}(x,y) = \sum_{m,n}^{M,N} d_{mn}^{xp} \Psi_{mn}^{xp}(x,y)$$
 (2)

where the orthonormalized copolarized and cross-polarized hybrid modes Ψ_{mn}^{co} , Ψ_{mn}^{xp} are:

$$\Psi_{mn}^{co}(x,y) = \frac{\sqrt{2\epsilon_n}}{a} (-1)^{\frac{m+n-1}{2}} \cos(\frac{m\pi x}{a}) \cos(\frac{n\pi y}{a}) , |x| \le a/2, |y| \le a/2$$
 (3)

$$\Psi_{mn}^{xp}(x,y) = \frac{\sqrt{2\epsilon_n}}{a} (-1)^{\frac{m+n+1}{2}} \sin(\frac{m\pi x}{a}) \sin(\frac{n\pi y}{a}) , |x| \le a/2, |y| \le a/2$$
 (4)

In (3) and (4) the origin of the Cartesian coordinates is located at the geometrical center of the aperture and $\epsilon_n = 2 - \delta_{n0}$ is the Neumann number. The corresponding copolarized and cross-polarized modal coefficients of (3-4) are related to the modal coefficients of (1) through:

$$d_{mn}^{co} = \frac{nC_{mn} - mA_{mn}}{\sqrt{m^2 + n^2}} \quad , d_{mn}^{xp} = \frac{nA_{mn} + mC_{mn}}{\sqrt{m^2 + n^2}}.$$
 (5)

Now the coupling efficiency $\eta(w_o)$ of the aperture to a fundamental Gaussian beam of waist radius w_o , which has its waist on the aperture is given by [11]:

$$\eta(w_o) = \left| \sum_{m,n}^{M,N} d_{mn}^{co} I_{mn}(w_o) \right|^2 / \left(\frac{w_o^2 \pi}{2} \sum_{m,n}^{M,N} (|d_{mn}^{cp}|^2 + |d_{mn}^{xp}|^2) \right)$$
 (6)

where,
$$I_{mn}(w_o) = \iint_{apert.} \Psi_{mn}^{co}(x, y) exp(-(x^2 + y^2)/w_o^2) dx dy.$$
 (7)

We wish at this point to determine the modal coefficients d_{mn}^{co} and d_{mn}^{xp} so that the coupling efficiency $\eta(w_o)$ is maximized. For this purpose, the application of Schwarz's inequality to (6) immediately implies that the maximum coupling efficiency $\eta_{max}(w_o)$ occurs in the absence of cross-polarization and is obtained from:

$$\eta_{max}(w_o) = \frac{2}{w_o^2 \pi} \sum_{m,n}^{M,N} |I_{mn}(w_o)|^2$$
 (8)

with the corresponding co-polarization modal coefficients determined by:

$$d_{mn}^{co} / I_{mn}(w_o) = \text{constant}. \tag{9}$$

The condition for vanishing cross-polarization is (see 5):
$$nA_{mn} = -mC_{mn}$$
. (10)

Therefore, for maximum fundamental Gaussian coupling efficiency the aperture modes should add in phase and their relative magnitudes should satisfy conditions (9) and (10). The maximum coupling efficiency $\eta_{max}(w_o)$ of equation (9) still depends on the waist radius w_o and it is shown in figure 2 as a function of the ratio w_o/a for various indices (M,N). In table 1 we show the relative magnitudes between the modes at the optimum $w_{o,opt}/a$ ratio, for some practically encountered aperture sets of modes.

Available modes (M,N)	(1,0)	(1,2)	$(1,2) + TE_{30}$	(3,2)
$w_{o,opt}/a$	0.43	0.34	0.32	0.29
cpl. efficiency: η_{max}	84%	98.5%	99.2%	99.7%
d_{12}^{co}/d_{10}	-	0.51	0.56	0.64
d_{30}^{co}/d_{10}	-	-	0.11	0.17
d_{32}^{co}/d_{10}	-	-	-	-0.11

Table 1: Optimum parameters for maximum fundamental Gaussian coupling efficiency for certain practically encountered aperture modes available for beamshaping.

III. APPROXIMATE ANALYSIS OF THE MACHINED SECTION AND DESCRIPTION OF THE DESIGN PROCESS

Consider the gradually-flared pyramidal machined section of axial length L_M and of half flareangle θ_o (see fig. 1) which is assumed excited at its throat by M × N locally propagating modes. Since the machined section is gradually flared and the incident modes propagating, reflections at the throat are considered negligible and the corresponding transverse electric field is given by:

$$\bar{E}_{t,thr}(x,y) = \sum_{m,n}^{M,N} \{ A_{mn}^{th} \bar{e}_{mn}^{th,TE}(x,y) + C_{mn}^{th} \bar{e}_{mn}^{th,TM}(x,y) \} . \tag{11}$$

To a first order approximation we can assume that each mode preserves its carried power upon propagating from the throat to the aperture. Also, each mode acquires a phase shift computed by:

$$\Phi_{mn} = \int_0^{L_M} \beta_{mn}(z) \ dz \tag{12}$$

where $\beta_{mn}(z)$ is the local propagation constant of the mn^{th} -mode. The above phase shift has been used extensively for the design of multimode horns [9-10] and it can be rigorously justified through a coupled-mode analysis of gradually flared tapers [13]. The aperture field is assumed to be modulated by a quadratic phase factor $Q_{L_T}(x,y)$ of curvature $L_T=a/(2\tan\theta_o)$ with L_T being the total virtual length of the taper. Under the above assumptions and neglecting reflections, the aperture field is simply given by:

$$\bar{E}_{t,ap}(x,y) = Q_{L_T}(x,y) \sum_{m,n}^{M,N} \{ A_{mn}^{ap} \bar{e}_{mn}^{ap,TE}(x,y) + \hat{C}_{mn}^{ap} \bar{e}_{mn}^{ap,TM}(x,y) \}$$
 (13)

with the quadratically modulated aperture modal coefficients related to the throat modal coefficients through:

$$\hat{A}_{mn}^{ap} = A_{mn}^{th} \sqrt{Y_{mn}^{th,TE}/Y_o} \exp(-j\Phi_{mn}) , \hat{C}_{mn}^{ap} = C_{mn}^{th} \sqrt{Y_{mn}^{th,TM}/Y_o} \exp(-j\Phi_{mn})$$
(14)

where Y_{mn}^{th} is the throat admittance for the mn^{th} mode and Y_o is the free-space intrinsic admittance which has been assigned to the aperture modes. Based on the above simplified analysis for

the machined section and on a full-wave analysis of the integrated portion a three-stage design process has been established and is summarized below:

- 1. The integrated 70° flare-angle section of the antenna structure of figure 1 (including the step discontinuity) is selected and analyzed independently of the machined section. For this purpose, the dipole-fed integrated portion is assumed to be terminated by an infinite square waveguide of side (a_s + 2s) and is analyzed using the full-wave analysis technique of [2] to obtain the throat modal coefficients Ath_{mn}, Cth_{mn}. The junction cross-section a_s and the step size s (see fig. 1) are selected so that the magnitudes of the radiating aperture modal coefficients, as predicted by equations 5 and 14, satisfy the optimal conditions (9) and (10) as closely as possible.
- 2. The infinite waveguide is now replaced by the gradually flared machined section and the assumption is made that the modal coefficients at the throat of the machined section retain their computed values of stage 1. This is a good approximation since the actual excited modal coefficients are determined by the difference between the integrated portion flare-angle and the machined section flare-angle and this difference is always dominated by the large 70° flare-angle of the integrated portion [10]. The length L_M and the flare-angle θ_o of the machined section are then selected iteratively (using 12) so that the modal coefficients d^{co}_{mn} appear in phase on the radiating aperture. The shortest possible length is chosen in order to achieve the maximum bandwidth.
- 3. Finally, the length and the flare-angle of the machined section are "fine-tuned" using the full-wave analysis of [2] for the entire quasi-integrated horn antenna and again for achieving maximum Gaussian coupling efficiency.

In table 2 we quantify several practical geometries of integrated portions which have resulted from the first stage of the design process.

IV. NUMERICAL AND EXPERIMENTAL RESULTS FOR SPECIFIC QUASI-INTEGRATED HORN ANTENNA DESIGNS.

The algorithm of section III has been employed for the design of a 20dB, a 23dB and a 25dB quasi-integrated horn antenna, all with a fundamental Gaussian coupling efficiency exceeding 97% and with a full-null beam efficiency around 99%. Although, in the design process the analysis of the machined section is performed using the approximate method of section III, the computation of the radiation characteristics of the finally designed horns is carried out using the full-wave analysis technique of [2]. Furthermore, using this full-wave analysis along with 6GHz scale-model measurements it was verified that the input impedance of the feeding strip-dipole in the integrated portion of the horn is not affected by the attachment of the machined section [3]. This is due to the fact that the input impedance of the feeding strip is mainly determined by its local geometrical environment which remains unaffected by the attachment of the machined section. The input impedance for the integrated-circuit horn antennas has already been analyzed theoretically and characterized experimentally in [2] where it was shown that by adjusting the dipole position inside the horn, the input impedance can be matched to either Schottky or SIS diodes. Therefore, the results of [2] are directly applicable to the case of the quasi-integrated horn antennas as well.

A. 20dB quasi-integrated horn antenna.

The geometrical parameters for the 20dB realization are calculated to be $(a_s = 1.35\lambda, s = 0.0, L_M = 7\lambda, \theta_o = 9^\circ, dp = 0.39\lambda)$ and the numerically computed patterns from the third stage of the design process along with the corresponding 90GHz measurements have been reported in [3]. In fig. 3 the principal patterns are compared to the patterns obtained by analyzing the machined section using the approximate method of section III. As shown, the approximate model agrees well with both the full-wave analysis and the measurements thus verifying the approximations used in the design process. The main radiation characteristics of this horn at

the design frequency and at the edges of the $\pm 5\%$ bandwidth are summarized in table 3. The indicated 10-dB beamwidth fluctuation corresponds to the variation of the beamwidth in an azimuthal far-field cut. The Gaussian-beam rolloff was calculated at the edges of the $\pm 5\%$ bandwidth using the Gaussian-beam parameters which were calculated at the design frequency f_o . The calculated phase center was found to be located at a distance of 1.5λ from the horn aperture for the E-plane and at 1.4λ for the H-plane.

B. 23dB quasi-integrated horn antenna.

The optimized design parameters for a 23dB quasi-integrated horn are found to be $(a_s = 1.52\lambda, s = 0.17\lambda, L_M = 13\lambda, \theta_o = 8.5^\circ, dp = 0.39\lambda)$ and the computed principal patterns from both the full-wave analysis of the entire antenna and from the approximate model of section III are compared in figure 4 to corresponding 370GHz measurements. In figure 5 we include also the computed from the full-wave analysis and the measured patterns for the 45°-plane. The radiation characteristics of this horn are being summarized in table 4. For the 23dB horn the phase center was calculated to be at 3.7λ inside the horn for the E-plane and at 3.5λ for the H-plane.

C. 25dB Quasi-integrated horn antenna.

In order to evaluate the efficiency of the design process and to provide a full range of practical designs, a 25dB quasi-integrated horn has also been designed and the computed geometrical parameters are found to be: $(a_s = 1.52\lambda, s = 0.0\lambda, L_M = 19.5\lambda, \theta_o = 10^o, dp = 0.39\lambda)$. The radiation patterns, as calculated from the full-wave analysis and shown in figure 6 still exhibit excellent circular symmetry, low cross-polarization and suppressed sidelobes. The location of the phase center for this horn was computed to be at a distance of 13λ from the aperture for the E-plane and at 11λ for the H-plane. The rest of the main radiation characteristics of this horn antenna are being tabulated in table 5.

	Optimum	$a_s = 1.35\lambda$	$a_s = 1.52\lambda$	$a_s = 1.35\lambda$	$a_s = 1.57\lambda$
		s = 0.0	s = 0.0	$s = 0.17\lambda$	s = 0.0
$ d_{12}^{co,ap} / d_{10}^{ap} $	0.56*	0.52	0.50	0.55	0.51
$ \acute{d}_{30}^{ap} / \acute{d}_{10}^{ap} $	0.114	-	0.11	0.117	0.146
$arg(\acute{C}^{ap}_{12}/\acute{A}^{ap}_{12})$	180°	200°	183°	182°	179^{o}
$ \acute{C}_{12}^{ap} / \acute{A}_{12}^{ap} $	2	4.5	4.4	5.1	4.3

Table 2: Comparison between the optimum aperture modal coefficients and the modal coefficients launched at the aperture by four practical integrated portion sections. The exciting dipole is positioned at a distance of 0.39λ from the apex of the horn. * The optimum ratio $|\dot{d}_{12}^{co,ap}|/|\dot{d}_{10}^{ap}|$ is 0.51 for the $a_s=1.35\lambda$ geometry which only triggers the TE_{10} , TE_{12}/TM_{12} modes.

	$0.95f_o$	f_o	$1.05 f_o$
Gain	19.4dB	$20\mathrm{dB}$	20.6dB
Aperture efficiency	60.6%	62.8%	65.4%
10dB Beamwidth	$37^{\circ} \pm 1^{\circ}$	$34^{\circ} \pm 1.2^{\circ}$	$32^{\circ} \pm 1.8^{\circ}$
Sidelobe-level (E-plane)	-23dB	$-27\mathrm{dB}$	-26.3dB
Cross-pol.(45°)	$-22.5\mathrm{dB}$	$-22.7\mathrm{dB}$	-23dB
Beam-efficiency (to -10dB)	85%	86%	86.5%
Gaussian Coupling	96.4%	97.3%	96.9%
Gaussian Coupling rolloff	95.5%	97.3%	96.5%

Table 3: The main radiation characteristics of the 20dB quasi-integrated horn antenna (see text).

	$0.965 f_o$	f_o	$1.035 f_o$
Gain	$22.2 \mathrm{dB}$	$22.8 \mathrm{dB}$	$23.6 \mathrm{dB}$
Aperture efficiency	48.5%	52%	58.4%
10dB Beamwidth	$27.6 \pm 0.2^{\circ}$	$25^{\circ} \pm 1.1^{\circ}$	$22.5^{\circ} \pm 1.3^{\circ}$
Sidelobe-level (E-plane)	-28dB	-33dB	$-29.8\mathrm{dB}$
Cross-pol.(45°)	$-20.5 \mathrm{dB}$	-21dB	-22 dB
Beam-efficiency (to -10dB)	86.6%	86%	86.6%
Gaussian Coupling	97.2%	97.3%	96.8%
Gaussian Coupling rolloff	96.3%	97.3%	96.0%

Table 4: The main radiation characteristics of the 23dB quasi-integrated horn antenna (see text).

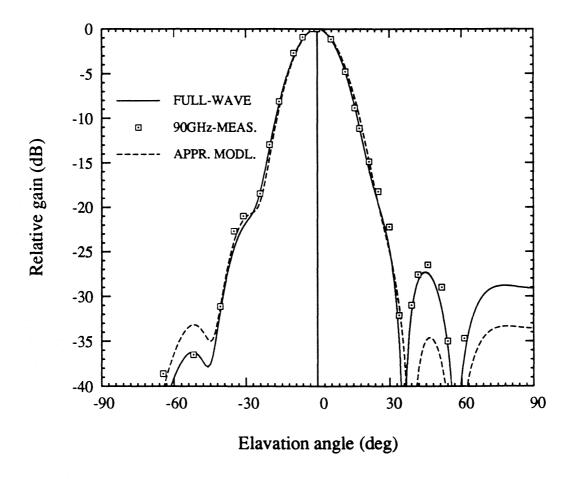
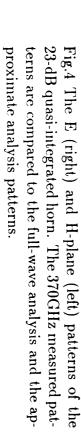
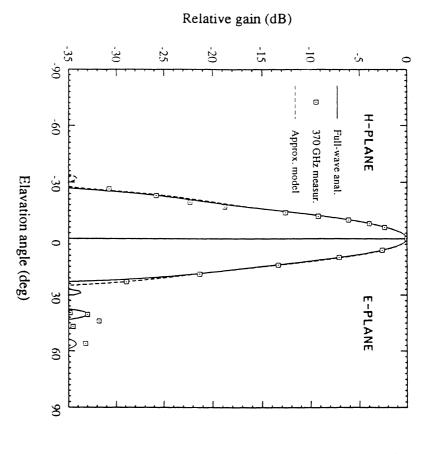
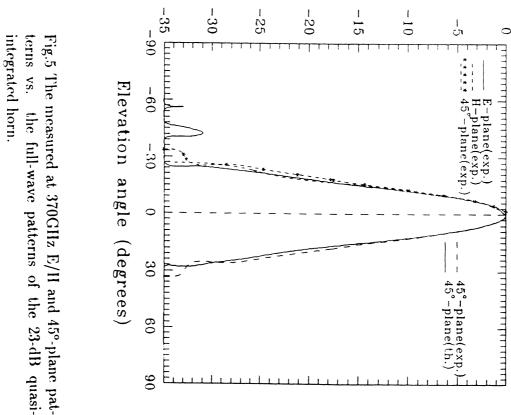


Fig.3 The E (right) and H-plane (left) patterns of the 20-dB quasiintegrated horn. The 90GHz measured patterns are compared to the full-wave analysis and the approximate analysis patterns. Detailed patterns including cross-polarization are shown in [3].





Relative gain (dB)



the full-wave patterns of the 23-dB quasi-

	$0.965 f_o$	f_o	$1.035 f_o$
Gain	$24.7\mathrm{dB}$	$25.5\mathrm{dB}$	$26.2\mathrm{dB}$
Aperture efficiency	36%	40%	44%
10dB Beamwidth	$21.6 \pm 0.8^{\circ}$	$19.2^{\circ} \pm 0.7^{\circ}$	$17.5^{\circ} \pm 0.5^{\circ}$
Sidelobe-level (E-plane)	$-28.7\mathrm{dB}$	-30.8 dB	$-30.8\mathrm{dB}$
Cross-pol.(45°)	-22.6dB	-24dB	−24.7dB
Beam-efficiency (to -10dB)	84.5%	85%	85%
Gaussian Coupling	97.1%	97.5%	97.4%
Gaussian Coupling rolloff	96.5%	97.5%	97.1%

Table 5: The main radiation characteristics of the 25dB quasi-integrated horn antenna (see text).

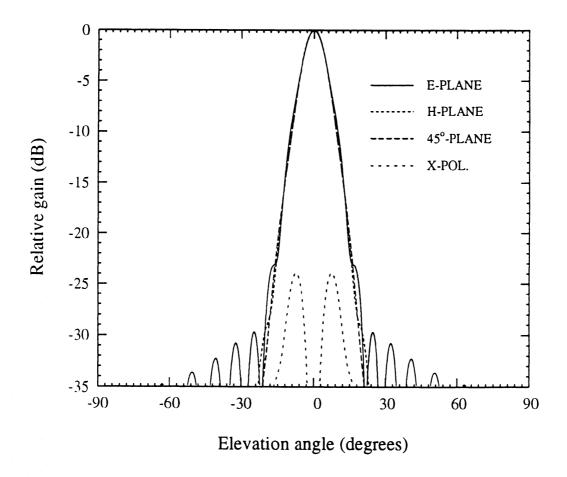


Figure 6: The calculated from the full-wave analysis patterns of the 25-dB quasi-integrated horn.

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PROGRESS IN INTEGRATED-CIRCUIT HORN ANTENNAS FOR RECEIVER APPLICATIONS

Part II: A 90 GHz Quasi-Integrated Horn Antenna Receiver

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ABSTRACT

A receiver belonging to the family of integrated planar receivers has been developed at 90 GHz. It consists of a planar Schottky-diode placed at the feed of a dipole-probe suspended inside an integrated horn antenna. The measured planar mixer single-sideband conversion loss at 91.2 GHz (LO) with a 200 MHz IF frequency is $8.3 dB \pm 0.3 dB$. The low cost of fabrication and simplicity of this design makes it ideal for millimeter and submillimeter-wave receivers.

INTRODUCTION

Fundamental mixers are currently the front-ends components for all millimeter-wave receivers above 100 GHz. The mixers use a Schottky-diode suspended in a machined waveguide with an appropriate RF matching network. These components are expensive to manufacture especially above 200 GHz where waveguide tolerances become severe. A low noise planar receiver consisting of a planar Schottky diode integrated with an efficient planar antenna is a needed alternative at millimeter-wave frequencies. Recent advances in planar Schottky diodes resulted in excellence performance at 94 GHz with measured diode temperatures competitive with whisker-contacted diodes [1]. In this work, a planar diode is combined with an integrated horn antenna [2,3] to yield a 90 GHz receiver. The antenna feed-dipole impedance can be designed to conjugate match the RF diode impedance [4]. This eliminates the need for an RF matching network and thereby simplifies the mixer design. A machined section is attached to the front of the integrated horn antenna to yield a multi-mode horn [5]. The planar configuration results in an inexpensive quasi-monolithic receiver with an expected performance as good as the best waveguide receiver at 100 GHz.

MIXER DESIGN AND THEORETICAL PERFORMANCE

The length of the feed-dipole and its position inside the integrated horn antenna are designed so that its impedance conjugate matches the RF diode impedance [4]. As a result, the planar diode is epoxied right at the dipole apex. An RF choke is obtained by using two integrated lumped capacitors on a coplanar stripline. The first capacitor is $\lambda_o/4$ away from the dipole feed and the second capacitor is $\lambda_d/2$ away from the first one. These capacitors introduce an RF open circuit at the dipole feed and let the IF signal pass through the coplanar stripline (Fig.1). The circuit is integrated on highly resistive Silicon in order to minimize any losses of the IF signal on the surrounding dielectric substrate. A microstrip quarter-wave transformer over a Duroid 5870 substrate [7] is used to match the 1.4 GHz IF diode output impedance to 50Ω . Fig.2 shows the structure of the integrated horn antenna receiver. The machined section, not shown in this figure, is attached to the front aperture of the horn antenna. Gold

is evaporated on all the horn walls except on the membrane wafer walls, in order not to short-out the feed lines. The diode of choice to be used in this design is the UVa SC2R4 planar Schottky diode with $2.5\mu m$ anode diameter, a 5-6fF zero-bias junction capacitance, a 12-13fF parasitic capacitance and a 5-6 Ω series resistance. A microwave model of the horn receiver structure shown in Fig.2 was built at 2.55 GHz in order to find the right feed-dipole impedance to conjugate match the UVa diode RF impedance. A feed-dipole, which is 0.392λ long and positioned 0.38λ from the apex of the horn, has an input impedance of 75+j55 Ω with the membrane walls uncoated and with no diode chip modeled at the dipole feeds. The input impedance dropped to 70+j10 Ω due to the capacitive effect of the diode block when it was modeled. A 1.1dB-1.3dB power loss was found in the microwave model by measuring the difference in powers detected by the feed-dipole for the case of coated and uncoated membrane walls respectively. Table I shows the mixer theoretical performance for the UVa diode at 91.2GHz(LO) and 91.4GHz(RF) for a bias of 0.65V and an available LO power of 2dBm. The analysis was done using the reflection algorithm [6]. the variation in conversion loss over 10% bandwidth is due to the variation in the feed dipole impedance.

Table I

$\mathrm{f}_{IF}(\mathrm{GHz})$	0.2
$f_{RF}(\mathrm{GHz})$	91.4
$\mathbf{Z}_{dipole,RF}(\Omega)$	70+j10
$Z_{dipole,2RF}(\Omega)$	14+j10
$Z_{diode,RF}^{in}(\Omega)$	62-j19
$Z_{diode,LO}^{in}(\Omega)$	55-j49
$Z_{diode,IF}^{out}(\Omega)$	86
Diode SC2R4 SSB Conversion loss(dB)	5.7
Diode SSB Conversion loss(dB) over 10% BW	5.7-6.2

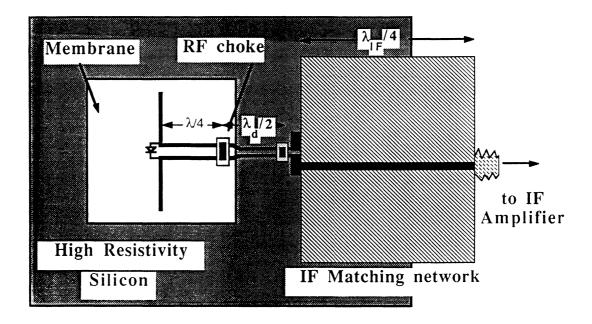


Figure 1: The mixer design consisting of the diode epoxied at the dipole feeds, the two lumped capacitors forming the RF choke, and the microstrip line IF matching network.

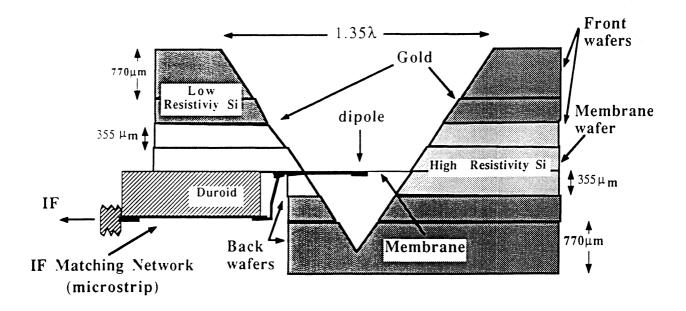


Figure 2: The integrated horn antenna receiver structure. The horn walls of the membrane wafer are not coated with gold.

RECEIVER MEASUREMENTS

A quasi-integrated horn antenna receiver was built at 91.4 GHz with a UVa SC2R4 diode epoxied at the dipole feeds. Video detection measurements were done at 91.4 GHz by shining a known plane wave power density onto the multi-mode antenna and measuring the output detected diode voltage using a lock-in amplifier. The diode theoretical video responsivity vs. bias current is fitted to the measured data by using the parameters shown in table II to model the receiver.

Table II

$\epsilon_{ ext{aperture}}$	$\epsilon_{ m lossinwalls}$	$\mathrm{Z}_{ extbf{dipole}}$	R_s	$C_{\mathbf{j}}$	$\phi_{ ext{bi}}$	$C_{\mathbf{p}}$	η
$-2.0\mathrm{dB}$	$-1.2 \mathrm{dB}$	70+j10 Ω	6Ω	5.5 fF	0.88 V	12.5 fF	1.14

In fig.3, the measured video responsivity is equal to the ratio of the detected voltage across the diode over the plane wave power incident on the aperture of the quasi-integrated horn antenna. The diode parameters used in the model are those provided by University of Virginia. Although the receiver was designed for a 1.4 GHz IF frequency, we found that epoxy and solder at the junction between the duroid and the silicon substrate have added a parasitic IF capacitance. The measurements were therefore done at 200 MHz where this capacitance has negligeable effect. For the SSB conversion loss measurement, a calibrated 91.4 GHz RF plane wave and a 91.2 GHz LO were combined using a thin Mylar sheet and shined on the receiver. Figure 4 shows the measured planar mixer SSB conversion loss. defined as the received IF power divided by the RF power absorbed by the horn aperture (plane wave power density \times horn area \times horn aperture efficiency). The SSB conversion loss includes the 1.2dB loss in the uncoated membrane walls. An 8.3dB SSB conversion loss is measured at 91.4 GHz with 3.5dBm estimated LO power available at the feed-dipole terminals. The coupling efficiency of the horn aperture to a plane wave is normalized out of the measurement because in a receiver system the horn has a gaussian coupling efficiency of 97%. Also, the measured result can be directly compared to waveguide mixers performance which have no antennas attached. The 8.3 dB SSB conversion loss compares favorably with the best waveguide mixers performance $(5.3\pm0.5dB)$ using the same diode [1].

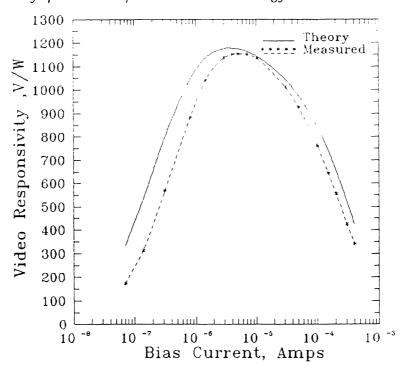


Figure 3: Measured and theoretical video responsivity at 91.4GHz.

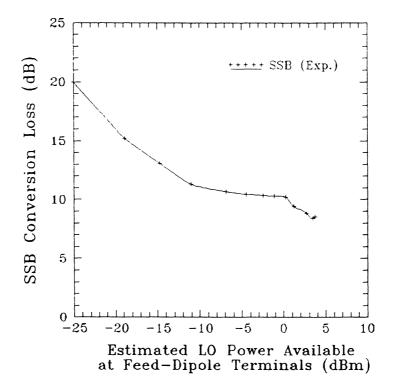


Figure 4: Measured planar mixer SSB conversion loss for the SC2R4 diode at 91.2 GHz (LO). The measured values include a 1.2dB loss attributed to power loss in the horn walls.

CONCLUSION

A 90GHz quasi-integrated horn antenna receiver has been designed and tested. The measurements show that this new receiver is a very good candidate for millimeter-wave applications. DSB measurements are being done on a new improved receiver design and using the UVa SC2T3 diode which has lower parasitic capacitance and series resistance than the UVa SC2R4 diode.

ACKNOWLEDGMENTS

This work was supported by the NASA/Center for Space Terahertz Technology at the University of Michigan, Ann Arbor. We thank G.V. Eleftheriades for the multi-mode horn design. We thank Dr. Thomas W. Crowe and William L. Bishop at the University of Virginia, for providing us with the diodes.

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